



Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from,Europe,America and south Asia,supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of “Quality Parts,Customers Priority,Honest Operation,and Considerate Service”,our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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**DBF60**

Silicon Diffused Junction Type

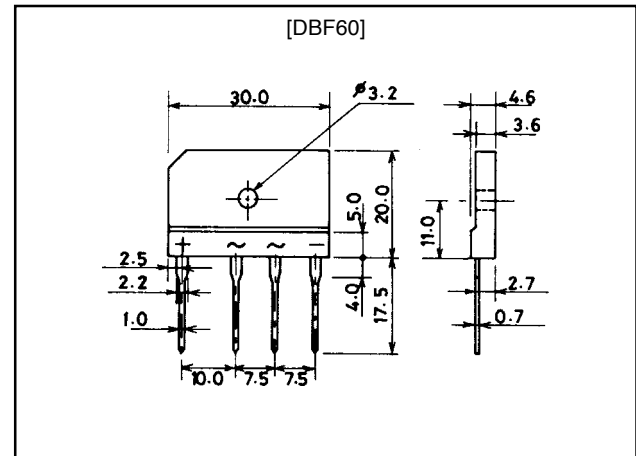
**6.0A Single-Phase Bridge Rectifier****Features**

- Glass passivation for high reliability.
- Plastic molded structure.
- Peak reverse voltage:  $V_{RM}=200, 600V$ .
- Average rectified current:  $I_O=6.0A$ .

**Package Dimensions**

unit:mm

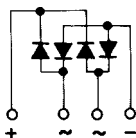
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**Specifications****Absolute Maximum Ratings at  $T_a = 25^\circ C$** 

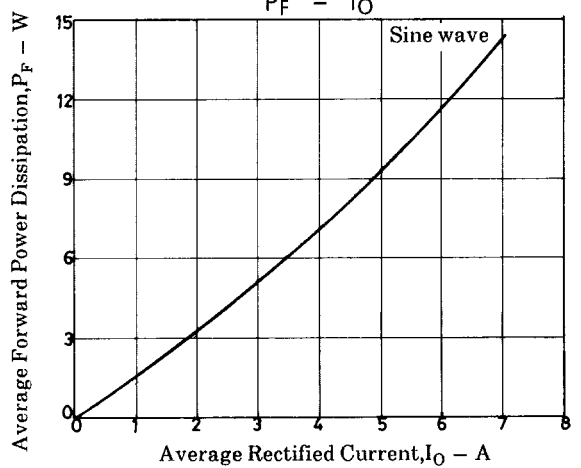
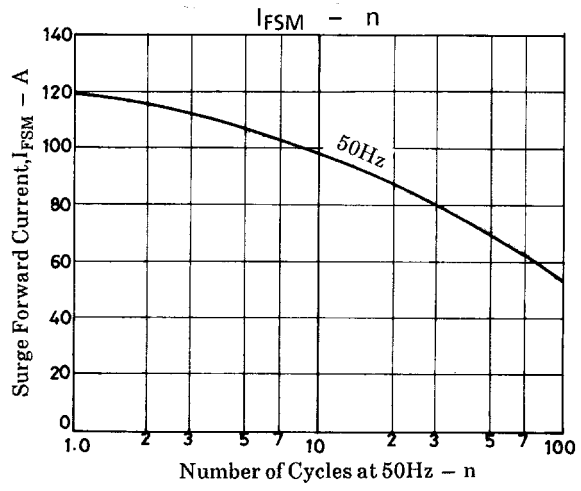
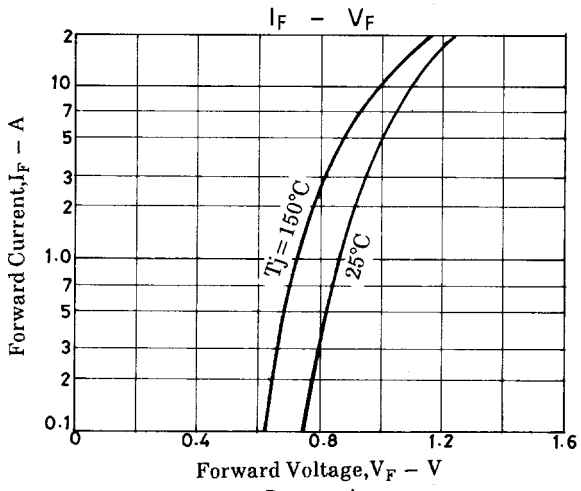
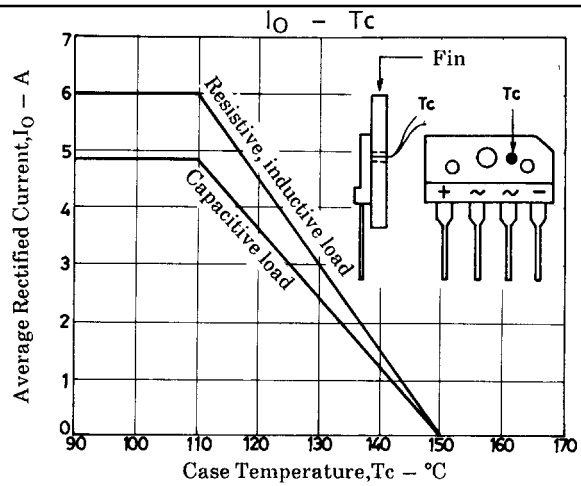
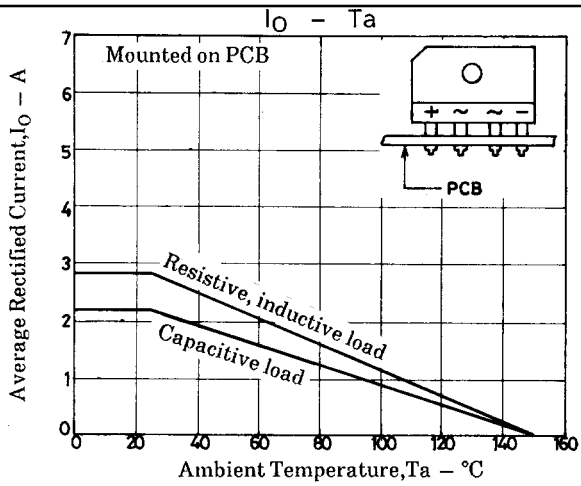
Parameter	Symbol	Conditions	<del>DBF60G</del>	DBF60G	Unit
Peak Reverse Voltage	$V_{RM}$		200	600	V
Average Rectified Current	$I_O$	$T_c=110^\circ C$ , with $125 \times 125 \times 1.5mm^3$ Al fin	→	6	A
		$T_a=25^\circ C$ , without fin	→	2.8	A
Surge Forward Current	$I_{FSM}$	50Hz sine wave, 1 cycle	→	120	A
Junction Temperature	$T_J$		→	150	$^\circ C$
Storage Temperature	$T_{stg}$		→	-40 to +150	$^\circ C$

**Electrical Characteristics at  $T_a = 25^\circ C$ , per constituent element of bridge.**

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Forward Voltage	$V_F$	$I_F=2.5A$			1.05	V
Reverse Current	$I_R$	$V_R$ :At each $V_{RM}$			10	$\mu A$
Thermal Resistance (Junction-Ambient)	$R_{th(j-a)}$	Without fin			26	$^\circ C/W$
Thermal Resistance (Junction-Case)	$R_{th(j-c)}$	With Al fin			3.4	$^\circ C/W$

**Electrical Connection**

# DBF60



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